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View Online at https://aerobasegroup.com/nsn/5961-01-223-1141

Inclosure Material:

Metal

Overall Length:

1.453 inches

Mounting Facility Quantity:

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-5

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case and quality assurance level tx

Overall Width Across Flats:

0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

115.5 regulator voltage

Voltage Tolerance In Percent:

-5.0/+5.0

Current Rating Per Characteristic:

430.00 milliamperes source cutoff current horsepower metric

Power Rating Per Characteristic:

50.0 watts any acceptable preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

Specification Data:

81349-mil-s-19500/358 government specification

Shelf Life:

N/a

- Unit Of Measure:
- --
- Demilitarization:

No

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